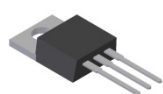


Features

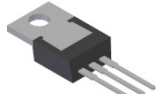
- Low Forward Voltage Drop
- Excellent High Temperature Stability
- Patented Super Barrier Rectifier Technology
- Soft, Fast Switching Capability
- **Lead Free Finish, RoHS Compliant (Note 2)**
- **Also Available in Green Molding Compound (Note 5)**

Mechanical Data

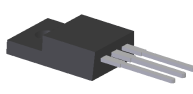
- Case: TO-220AB, ITO-220AB
- Case Material: Molded Plastic, UL Flammability Classification Rating 94V-0
- Terminals: Matte Tin Finish annealed over Copper leadframe. Solderable per MIL-STD-202, Method 208 
- Marking Information: See Page 3
- Ordering Information: See Page 3
- Weight: TO-220AB – 1.85 grams (approximate)
ITO-220AB – 1.65 grams (approximate)



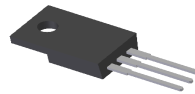
TO-220AB
Top View



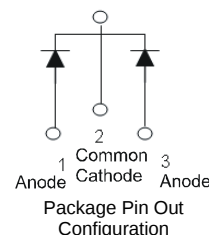
TO-220AB
Bottom View



ITO-220AB
Top View



ITO-220AB
Bottom View



Maximum Ratings @T_A = 25°C unless otherwise specified

Single phase, half wave, 60Hz, resistive or inductive load.
For capacitance load, derate current by 20%.

Characteristic	Symbol	Value	Unit
Peak Repetitive Reverse Voltage	V _{RRM}	60	V
Working Peak Reverse Voltage	V _{RWM}		
DC Blocking Voltage	V _{RM}		
Average Rectified Output Current @ T _C = 110°C	I _O	30	A
Non-Repetitive Avalanche Energy (T _J = 25°C, I _{AS} = 20A, L = 8.5mH, t _p = 1ms)	E _{AS}	400	mJ
Repetitive Peak Avalanche Energy (1μs, 25°C)	P _{ARM}	8600	W
Non-Repetitive Peak Forward Surge Current 8.3ms Single Half Sine-Wave Superimposed on Rated Load	I _{FSM}	250	A
Peak Repetitive Reverse Surge Current (2μs-1Khz)	I _{RRM}	3	A
Isolation Voltage (ITO-220AB Only) From terminal to heatsink t = 3 sec.	V _{AC}	2000	V

Thermal Characteristics

Characteristic	Symbol	Value	Unit
Typical Thermal Resistance (per leg)	R _{θJA}	10.6	°C/W
Thermal Resistance Junction to Ambient (Note 3)			
Thermal Resistance Junction to Case (Note 3)	R _{θJC}	0.6	
Operating and Storage Temperature Range	T _J , T _{STG}	-65 to +150	°C

Electrical Characteristics @T_A = 25°C unless otherwise specified

Characteristic	Symbol	Min	Typ	Max	Unit	Test Condition
Forward Voltage Drop	V _F	-	0.53	0.60 0.55	V	I _F = 15A, T _J = 25°C I _F = 15A, T _J = 125°C
Leakage Current (Note 1)	I _R	-	-	0.5 100	mA	V _R = 60V, T _J = 25°C V _R = 60V, T _J = 125°C

- Notes:
1. Short duration pulse test used to minimize self-heating effect.
 2. EU Directive 2002/95/EC (RoHS). All applicable RoHS exemptions applied, see *EU Directive 2002/95/EC Annex Notes*.
 3. Test Device on Heatsink (Black Aluminum, 37mm * 50mm* 15mm)

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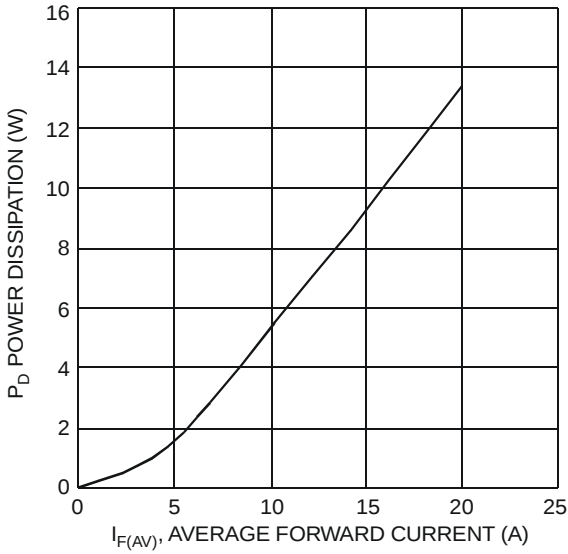


Fig. 1 Forward Power Dissipation

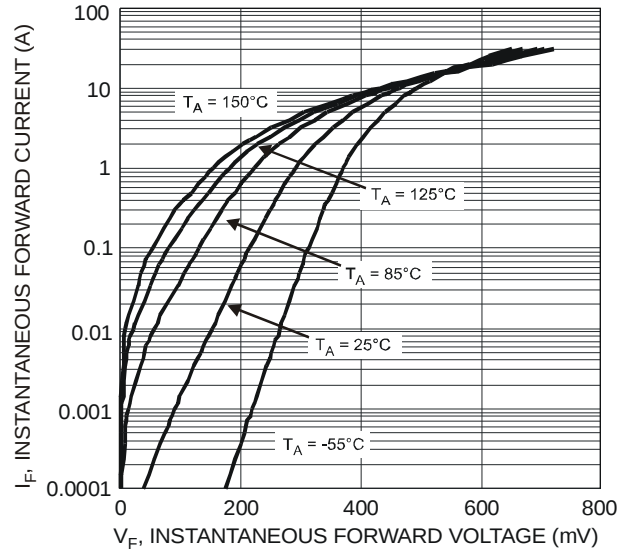


Fig. 2 Typical Forward Characteristics

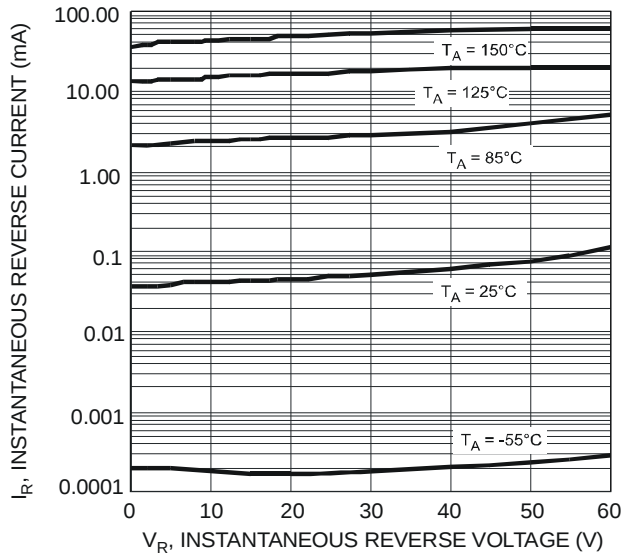


Fig. 3 Typical Reverse Characteristics

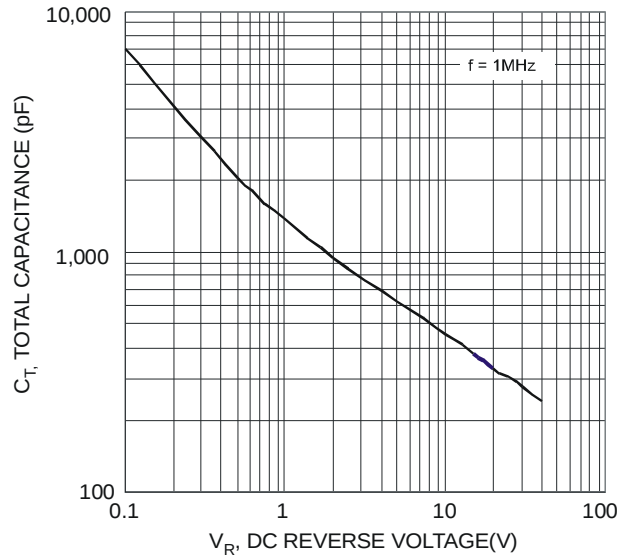


Fig. 4 Total Capacitance vs. Reverse Voltage

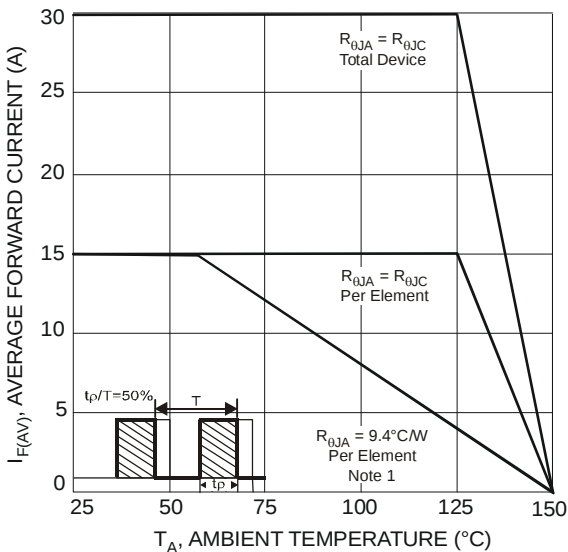


Fig. 5 Forward Current Derating Curve

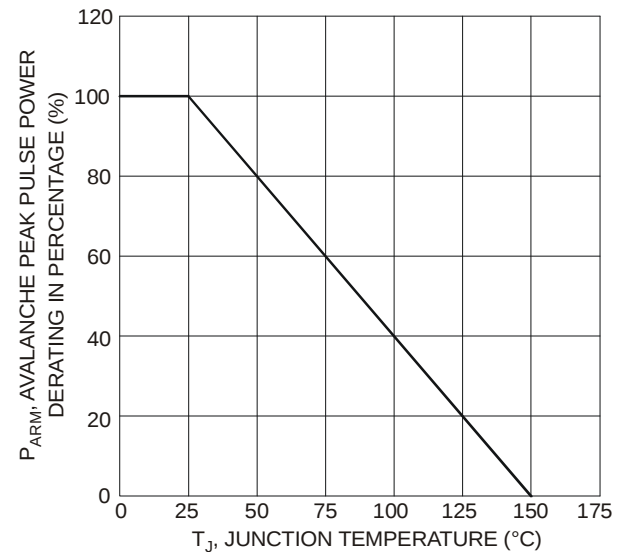


Fig. 6 Pulse Derating Curve

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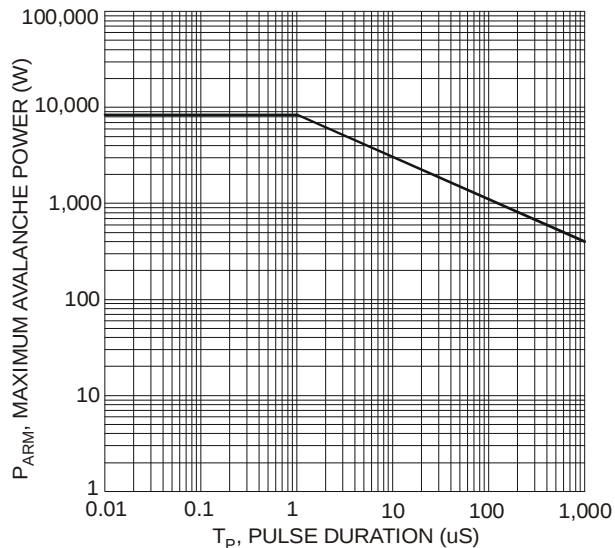


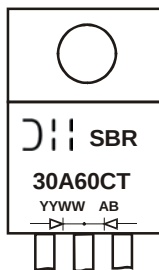
Fig. 7 Maximum Avalanche Power Curve

Ordering Information (Notes 4 & 5)

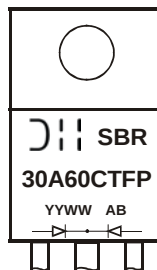
Part Number	Case	Packaging
SBR30A60CT	TO-220AB	50 pieces/tube
SBR30A60CT-G	TO-220AB	50 pieces/tube
SBR30A60CTFP	ITO-220AB	50 pieces/tube
SBR30A60CTFP-G	ITO-220AB	50 pieces/tube

Notes: 4. For packaging details, go to our website at <http://www.diodes.com/datasheets/ap02007.pdf>.
5. For Green Molding Compound version part numbers, add "-G" suffix to part number above. Examples: SBR30A60CT-G.

Marking Information

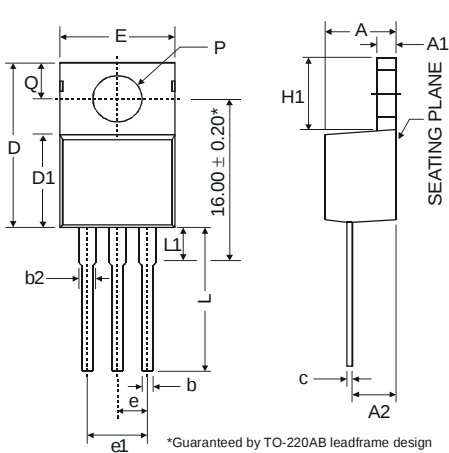


SBR30A60CT = Product Type Marking Code
AB = Foundry and Assembly Code
YYWW = Date Code Marking
YY = Last two digits of year (ex: 06 = 2006)
WW = Week (01-52)

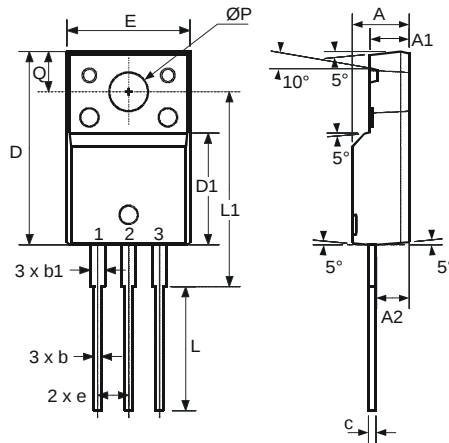


SBR30A60CTFP = Product Type Marking Code
AB = Foundry and Assembly Code
YYWW = Date Code Marking
YY = Last two digits of year (ex: 06 = 2006)
WW = Week (01-52)

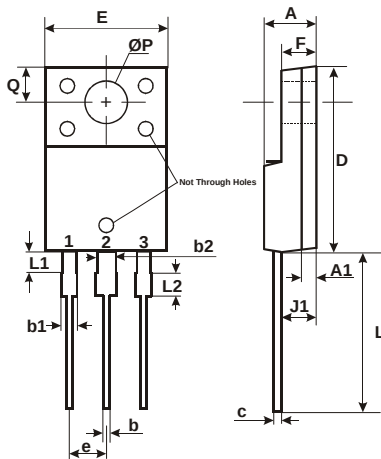
Package Outline Dimensions



TO-220AB			
Dim	Min	Typ	Max
A	3.56	-	4.82
A1	0.51	-	1.39
A2	2.04	-	2.92
b	0.39	0.81	1.01
b2	1.15	1.24	1.77
c	0.356	-	0.61
D	14.22	-	16.51
D1	8.39	-	9.01
e	2.54		
e1	5.08		
E	9.66	-	10.66
H1	5.85	-	6.85
L	12.70	-	14.73
L1	-	-	6.35
P	3.54	-	4.08
Q	2.54	-	3.42
All Dimensions in mm			



ITO-220AB (Note 6)			
Dim	Min	Typ	Max
A	4.50	4.70	4.90
A1	3.04	3.24	3.44
A2	2.56	2.76	2.96
b	0.50	0.60	0.75
b1	1.10	1.20	1.35
c	0.50	0.60	0.70
D	15.67	15.87	16.07
D1	8.99	9.19	9.39
e	2.54		
E	9.91	10.11	10.31
L	9.45	9.75	10.05
L1	15.80	16.00	16.20
P	2.98	3.18	3.38
Q	3.10	3.30	3.50
All Dimensions in mm			



ITO-220AB ALTERNATE (Note 6)		
DIM.	MIN.	MAX.
A	4.30	4.70
A1	1.3	
b	0.50	0.75
b1	1.10	1.35
b2	1.50	1.75
c	0.50	0.75
D	14.80	15.20
E	9.96	10.36
e	2.54 typ	
F	2.80	3.20
J1	2.50	2.90
L	12.80	13.60
L1	1.70	1.90
L2	1.90	2.10
ØP	3.50 typ	
Q	2.70 typ	
All Dimensions in mm		

Notes: 6. For product manufactured with Date Code 0733 (week 33, 2007) and newer, please refer to ITO-220AB dimensions. For product manufactured prior to Date Code 0733, please refer to ITO-220AB ALTERNATE dimensions.

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